

NPN-Silizium-Fototransistor
Silicon NPN Phototransistor
Lead (Pb) Free Product - RoHS Compliant

SFH 310
SFH 310 FA



SFH 310



SFH 310 FA

Not for new design (valid till DC0837, additional information see OS-PCN-2006-015-A)

Wesentliche Merkmale

- Speziell geeignet für Anwendungen im Bereich von 400 nm bis 1100 nm (SFH 310) und bei 880 nm (SFH 310 FA)
- Hohe Linearität
- 3 mm-Plastikbauform

Features

- Especially suitable for applications from 400 nm to 1100 nm (SFH 310) and of 880 nm (SFH 310 FA)
- High linearity
- 3 mm plastic package

Anwendungen

- Lichtschranken für Gleich- und Wechsellichtbetrieb
- Industrieelektronik
- „Messen/Steuern/Regeln“

Applications

- Photointerrupters
- Industrial electronics
- For control and drive circuits

Typ Type	Bestellnummer Ordering Code
SFH 310	Q62702P0874
SFH 310-2/3	Q62702P3595
SFH 310 FA	Q62702P1673
SFH 310 FA-2/3	Q62702P3596

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	– 40 ... + 100	°C
Kollektor-Emitterspannung Collector-emitter voltage	V_{CE}	70	V
Kollektorstrom Collector current	I_C	50	mA
Kollektorspitzenstrom, $\tau < 10 \mu s$ Collector surge current	I_{CS}	100	mA
Verlustleistung, $T_A = 25 \text{ °C}$ Total power dissipation	P_{tot}	165	mW
Wärmewiderstand Thermal resistance	R_{thJA}	450	K/W

Kennwerte ($T_A = 25\text{ °C}$, $\lambda = 950\text{ nm}$)

Characteristics

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		SFH 310	SFH 310 FA	
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S\text{ max}}$	780	880	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von S_{max} Spectral range of sensitivity $S = 10\%$ of S_{max}	λ	470 ... 1070	740 ... 1070	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	A	0.19	0.19	mm ²
Abmessung der Chipfläche Dimensions of chip area	$L \times B$ $L \times W$	0.65×0.65	0.65×0.65	mm × mm
Halbwinkel Half angle	φ	± 25	± 25	Grad deg.
Kapazität, $V_{\text{CE}} = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ Capacitance	C_{CE}	10	10	pF
Dunkelstrom Dark current $V_{\text{CE}} = 10\text{ V}$, $E = 0$	I_{CEO}	5 (≤ 50)	5 (≤ 50)	nA
Fotostrom Photocurrent $E_e = 0.5\text{ mW/cm}^2$, $V_{\text{CE}} = 5\text{ V}$ $E_v = 1000\text{ lx}$, Normlicht/standard light A, $V_{\text{CE}} = 5\text{ V}$	I_{PCE} I_{PCE}	≥ 0.4 4	≥ 0.4 —	mA mA

Die Fototransistoren werden nach ihrer Fotoempfindlichkeit gruppiert und mit arabischen Ziffern gekennzeichnet.

The phototransistors are grouped according to their spectral sensitivity and distinguished by arabian figures.

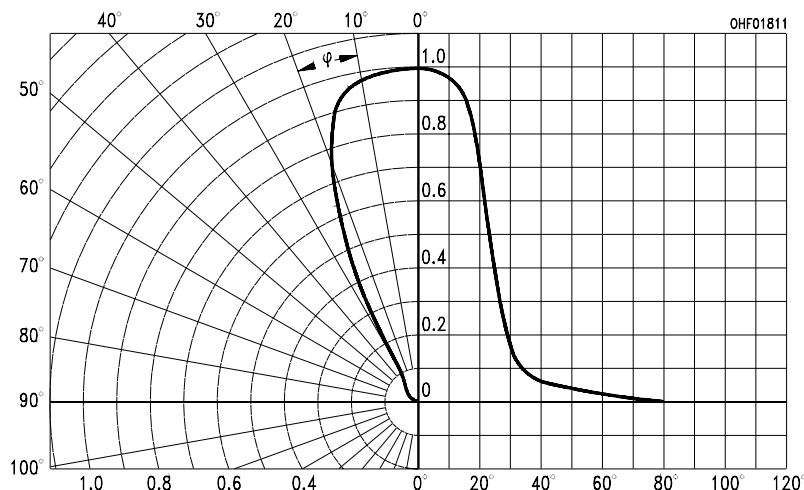
Bezeichnung Parameter	Symbol Symbol	Wert Value				Einheit Unit
		-1	-2	-3	-4	
Fotostrom, $\lambda = 950 \text{ nm}$ Photocurrent $E_e = 0.5 \text{ mW/cm}^2$, $V_{CE} = 5 \text{ V}$ SFH 310: $E_v = 1000 \text{ lx}$, Normlicht/ standard light A, $V_{CE} = 5 \text{ V}$	I_{PCE}	0.4 ... 0.8	0.63 ... 1.25	1.0 ... 2.0	1.6 ... 3.2	mA
	I_{PCE}	2.1	3.4	5.4	8.6	mA
Anstiegszeit/Abfallzeit Rise and fall time $I_C = 1 \text{ mA}$, $V_{CC} = 5 \text{ V}$, $R_L = 1 \text{ k}\Omega$	t_r, t_f	5	7	8	12	μs
Kollektor-Emitter-Sättigungsspannung Collector-emitter saturation voltage $I_C = I_{PCEmin}^{1)} \times 0.3$, $E_e = 0.5 \text{ mW/cm}^2$	V_{CEsat}	150	150	150	150	mV

¹⁾ I_{PCEmin} ist der minimale Fotostrom der jeweiligen Gruppe.

¹⁾ I_{PCEmin} is the min. photocurrent of the specified group.

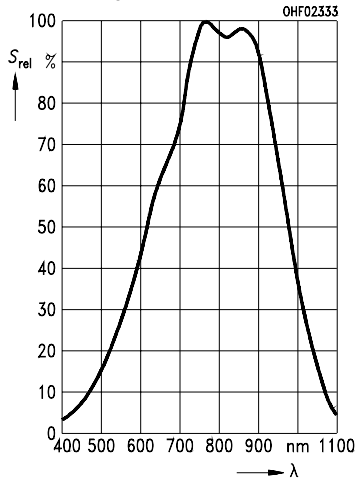
Directional Characteristics

$$S_{rel} = f(\varphi)$$

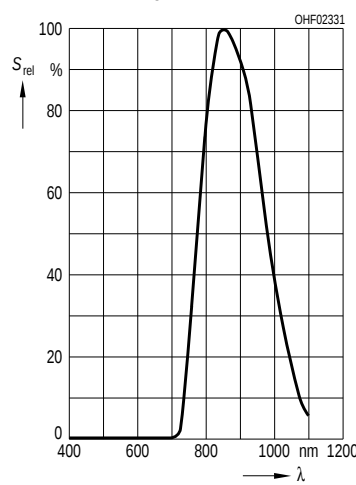


$T_A = 25^\circ\text{C}$, $\lambda = 950\text{ nm}$

Relative Spectral Sensitivity,
SFH 310 $S_{\text{rel}} = f(\lambda)$

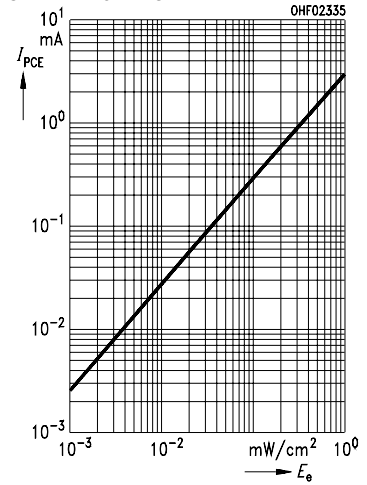


Relative Spectral Sensitivity,
SFH 310 FA $S_{\text{rel}} = f(\lambda)$



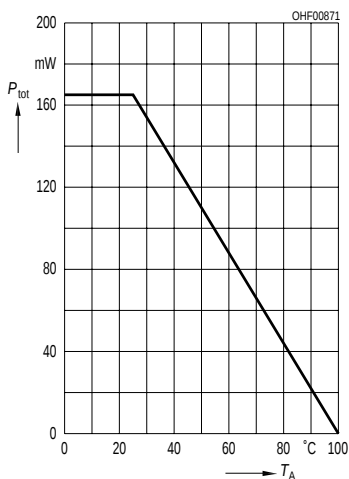
Photocurrent

$I_{\text{PCE}} = f(E_e)$, $V_{\text{CE}} = 5\text{ V}$



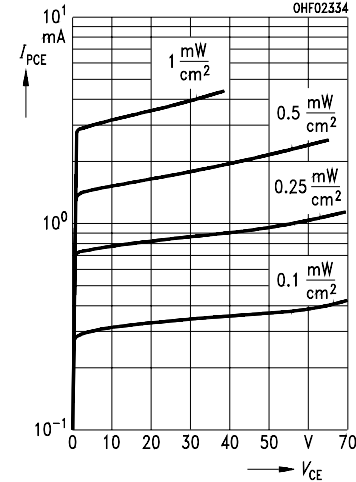
Total Power Dissipation

$P_{\text{tot}} = f(T_A)$



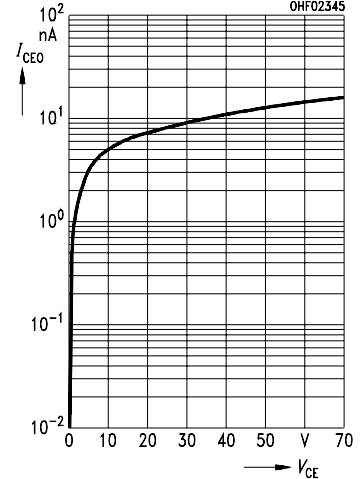
Photocurrent

$I_{\text{PCE}} = f(V_{\text{CE}})$, $E_e = \text{Parameter}$



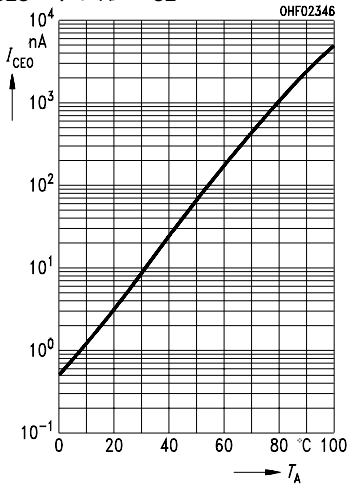
Dark Current

$I_{\text{CEO}} = f(V_{\text{CE}})$, $E = 0$



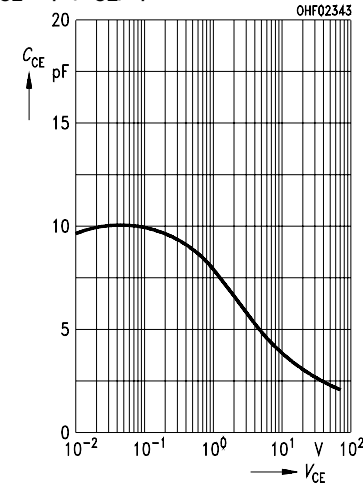
Dark Current

$I_{\text{CEO}} = f(T_A)$, $V_{\text{CE}} = 10\text{ V}$, $E = 0$



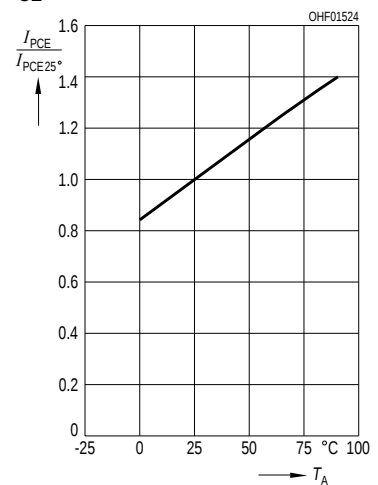
Capacitance

$C_{\text{CE}} = f(V_{\text{CE}})$, $f = 1\text{ MHz}$

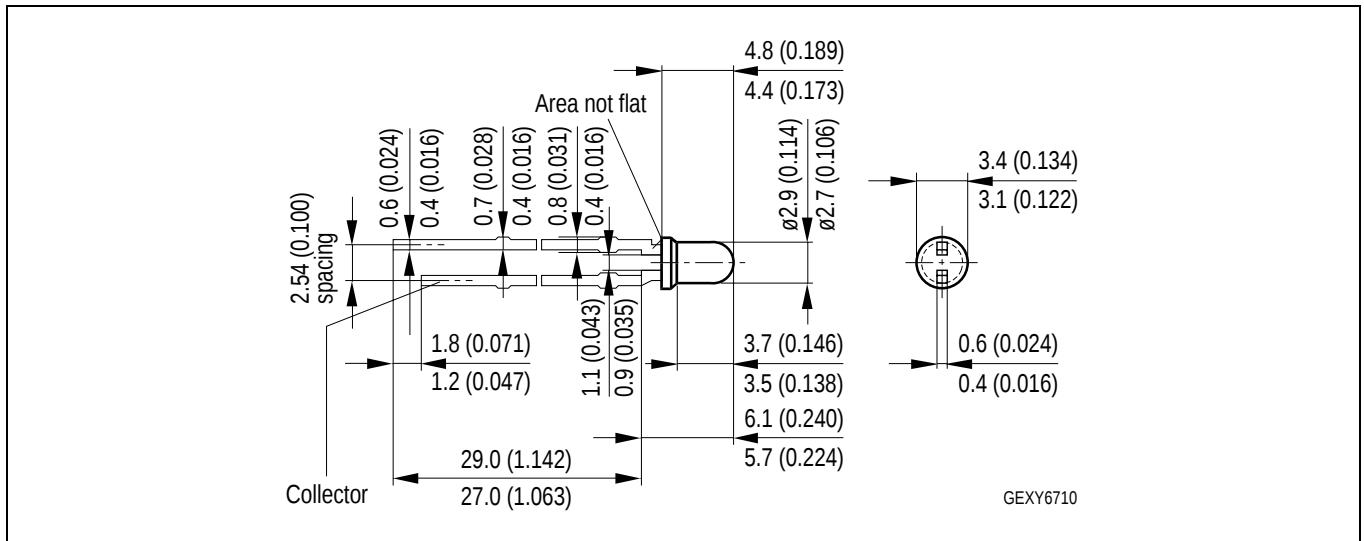


Photocurrent $I_{\text{PCE}} = f(T_A)$,

$V_{\text{CE}} = 5\text{ V}$, normalized to 25°C



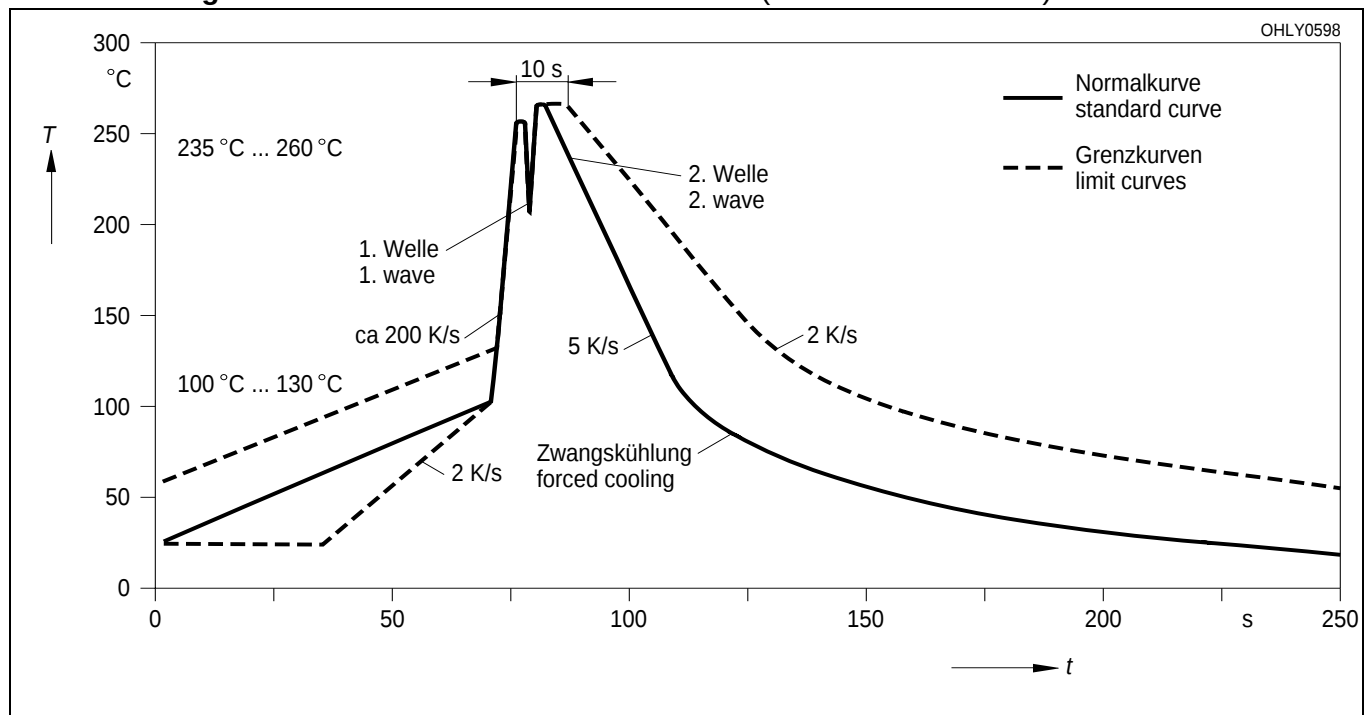
Maßzeichnung Package Outlines



Maße in mm (inch) / Dimensions in mm (inch).

Lötbedingungen Soldering Conditions Wellenlöten (TTW) TTW Soldering

(nach CECC 00802)
(acc. to CECC 00802)



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